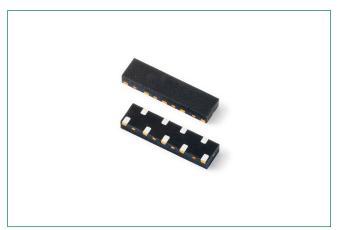
0.3pF Diode Array, Low Capacitance ESD Protection





Note: This package image is for example and reference only. for detail package drawing, please refer to the package section in this datasheet.

Pinout

Line-2 Line-4 Line-5 Line-7 9 8 7 6 1 2 3 4 5 Line-1 Line-3 GND Line-6 Line-8

Top View

Line-1	Line-3	GND	Line-6	Line-8
1	2	3	4	5
g	8]	7 6	5

Line-2 Line-4 Line-5 Line-7

Bottom View

Description

The SC7538 integrates 8 channels of ultra low capacitance rail-to-rail diodes and an additional zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). This robust device can safely absorb repetitive ESD strikes above the maximum level maximum level, ±8kV contact discharge, as specified in the international standard IEC 61000-4-2, without performance degradation standard (±8kV contact discharge) without performance degradation. The extremely low loading capacitance also makes it ideal for protecting high speed signal pins such as V-By-One, HDMI, USB3.0, USB2.0, and IEEE 1394.

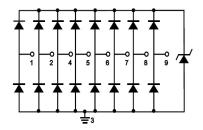
Features & Benefits

- ESD, IEC 61000-4-2, ±22kV contact, ±30kV air
- EFT, IEC 61000-4-4, 40A (t_p=5/50ns)
- Surge Tolerance, IEC 61000-4-5 2nd edition, 3A (t_p=8/20µs)
- Low capacitance of 0.3pF@0V, 3GHz (TYP) per I/O
- Low leakage current of 0.5μA (MAX) at 5V
- Halogen free, Lead free and RoHS compliant

Applications

- V-By-One
- Embedded DisplayPort
- USB 2.0/3.0 Ports
- HDMI
- Flat Panel Displays
- LCD/LED TVs
- Smartphones
- Mobile Computing

Functional Block Diagram



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications
The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.



0.3pF Diode Array, Low Capacitance ESD Protection

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I _{PP}	Peak Current (t _p =8/20µs)	3.0	А
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

Caution: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

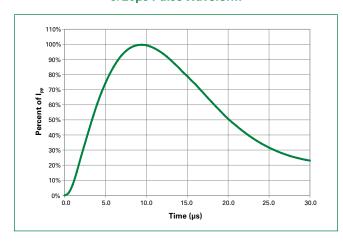
Electrical Characteristics (T_{OP}=25°C)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Standoff Voltage	V_{RWM}	Pin-1,-2,-4,-5,-6,-7,-8,-9 to pin-3			5	V
Breakdown Voltage	$V_{_{\mathrm{BR}}}$	I _R =1mA	6			V
Reverse Leakage Current	I _{LEAK}	V_R =5V, I/O to GND			0.5	μΑ
Clamp Voltage ¹	V _c	$I_{pp} = 1A$, $t_{p} = 8/20 \mu s$, Fwd		9.9		\/
		$I_{pp} = 2A$, $t_p = 8/20 \mu s$, Fwd		10.9		V
Dynamic Resistance ²	R_{DYN}	TLP, t_p =100ns, I/O to GND		0.42		Ω
ESD Withstand Voltage ^{1,3}	\/	IEC 61000-4-2 (Contact Discharge)	±22			kV
	V _{ESD}	IEC 61000-4-2 (Air Discharge)	±30			kV
Diode Capacitance ¹	C _{I/O-GND}	Reverse Bias=0V, f=3GHz		0.3		pF

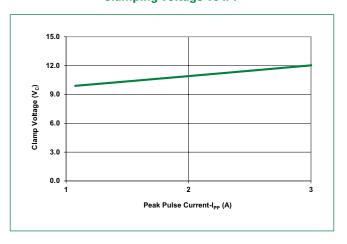
Notes:

- ${\it 1. Parameter is guaranteed by design and/or component characterization.}\\$
- 2. Transmission Line Pulse (TLP) test setting: Std.TDR(50Ω),tp=100ns, tr=0.2ns ITLP and VTLP averaging window: start t1=70ns to end t2=90ns
- 3. Device stressed with ten non-repetitive ESD pulses.

8/20µs Pulse Waveform



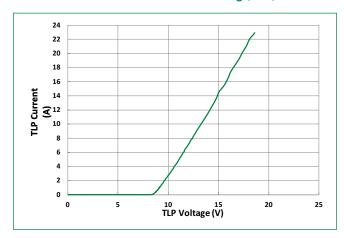
Clamping Voltage vs IPP



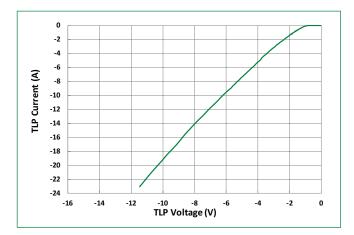


0.3pF Diode Array, Low Capacitance ESD Protection

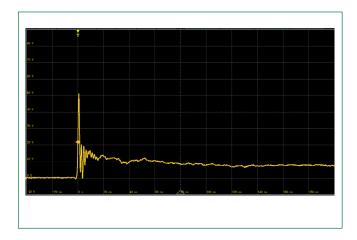
Positive Transmission Line Pulsing (TLP) Plot



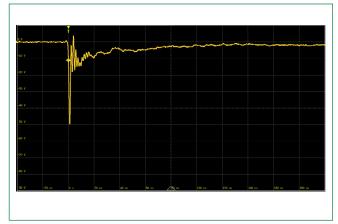
Negative Transmission Line Pulsing (TLP) Plot



IEC 61000-4-2 +8 kV Contact ESD Clamping Voltage



IEC 61000-4-2 -8 kV Contact ESD Clamping Voltage

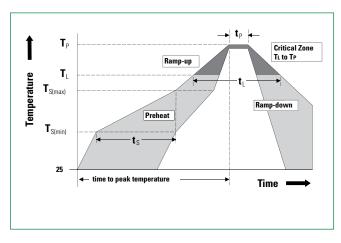




0.3pF Diode Array, Low Capacitance ESD Protection

Soldering Parameters

Reflow Condition		Pb – Free assembly		
	- Temperature Min (T _{s(min)})	150°C		
Pre Heat	-Temperature Max (T _{s(max)})	200°C		
	-Time (min to max) (t _s)	60 - 120 secs		
Average ram peak	np up rate (Liquidus) Temp (T _L) to	3°C/second max		
T _{S(max)} to T _L - Ramp-up Rate		3°C/second max		
Reflow	- Temperature (T _L) (Liquidus)	217°C		
	- Temperature (t _L)	60 - 150 seconds		
Peak Temperature (T _p)		260 ^{+0/-5} °C		
Time within 5°C of actual peak Temperature (tp)		30 seconds		
Ramp-down Rate		6°C/second max		
Time 25°C to peak Temperature (T _p)		8 minutes Max.		
Do not exce	ed	260°C		



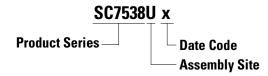
Ordering Information

Part Number	Package	Min. Order Qty.
SC7538-08UTG	μDFN-9	3000

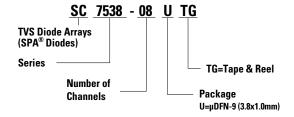
Product Characteristics

Lead Plating	Matte Tin
Lead material	Copper Alloy
Substrate Material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0

Part Marking System



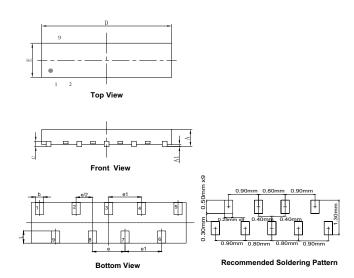
Part Numbering System





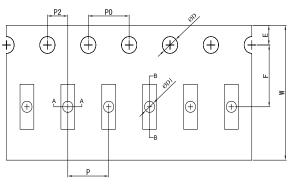
0.3pF Diode Array, Low Capacitance ESD Protection

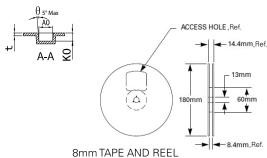
Package Dimensions

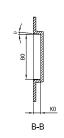


μDFN-9 (3.8x1.0mm)							
Cumbal	Millimeters			Inches			
Symbol	Min	Nom	Max	Min	Nom	Max	
Α	0.45	0.50	0.55	0.018	0.020	0.022	
A 1	-	0.02	0.05	-	0.001	0.002	
b	0.15	0.20	0.25	0.006	0.008	0.010	
C	0.10	0.15	0.20	0.004	0.006	0.008	
D	3.70	3.80	3.90	0.146	0.150	0.154	
е	0.80 BSC			0.	031 BSC		
e1	0.90 BSC			0.035 BSC			
E	0.90	1.00	1.10	0.035	0.039	0.043	
L	0.20	0.30	0.40	0.008	0.012	0.016	

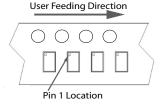
Embossed Carrier Tape & Reel Specification







Symbol	Millimeters
A0	1.35 +/- 0.10
В0	4.00 +/- 0.05
D	Ø 1.50 + 0.1/-0
D1	Ø 1.00 +/-0.05
E	1.75 +/- 0.10
F	5.50 +/- 0.05
K0	0.72 +/- 0.05
P	4.00 +/- 0.10
P0	4.00 +/- 0.10
P2	2.00 +/- 0.05
Т	0.25 +/- 0.02
W	12.00 + 0.30 /- 0.10



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